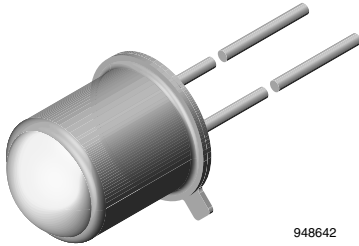


Silicon PIN Photodiode, RoHS Compliant



FEATURES

- Package type: leaded
- Package form: TO-18
- Dimensions (in mm): $\varnothing$ 4.7
- Radiant sensitive area (in mm²): 0.78
- High photo sensitivity
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity: $\varphi = \pm 12^\circ$
- Hermetically sealed package
- Cathode connected to package
- Central chip alignment
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS
COMPLIANT

DESCRIPTION

BPW24R is a high sensitive silicon planar photodiode in a standard TO-18 hermetically sealed metal case with a glass lens.

A precise alignment of the chip gives a good coincidence of mechanical and optical axes. The device features a low capacitance and high speed even at low supply voltages.

APPLICATIONS

- High speed photo detector

PRODUCT SUMMARY

COMPONENT	I_{ra} (μ A)	φ (deg)	$\lambda_{0.5}$ (nm)
BPW24R	60	± 12	600 to 1050

Note

Test condition see table "Basic Characteristics"

ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
BPW24R	Bulk	MOQ: 1000 pcs, 1000 pcs/bulk	TO-18

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	60	V
Power dissipation	$T_{amb} \leq 25^\circ\text{C}$	P_V	210	mW
Junction temperature		T_j	125	$^\circ\text{C}$
Operating temperature range		T_{amb}	- 40 to + 125	$^\circ\text{C}$
Storage temperature range		T_{stg}	- 40 to + 125	$^\circ\text{C}$
Soldering temperature	$t \leq 5$ s	T_{sd}	260	$^\circ\text{C}$
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm ²	R_{thJA}	350	K/W

Note

$T_{amb} = 25^\circ\text{C}$, unless otherwise specified

BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Breakdown voltage	$I_R = 100 \mu A, E = 0$	$V_{(BR)}$	60	200		V
Reverse dark current	$V_R = 50 V, E = 0$	I_{ro}		2	10	nA
Diode capacitance	$V_R = 0 V, f = 1 \text{ MHz}, E = 0$	C_D		11		pF
	$V_R = 5 V, f = 1 \text{ MHz}, E = 0$	C_D		3.8		pF
	$V_R = 20 V, f = 1 \text{ MHz}, E = 0$	C_D		2.5		pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	V_o		450		mV
Temperature coefficient of V_o	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK_{V_o}		- 2		mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	I_k		55		μA
Temperature coefficient of I_k	$E_A = 1 \text{ klx}$	TK_{I_k}		0.1		%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, V_R = 20 V$	I_{ra}	45	60		μA
Absolute Spectral Sensitivity	$V_R = 5 V, \lambda = 870 \text{ nm}$	$s(\lambda)$		0.60		A/W
	$V_R = 5 V, \lambda = 900 \text{ nm}$	$s(\lambda)$		0.55		A/W
Angle of half sensitivity		ϕ		± 12		deg
Wavelength of peak sensitivity		λ_p		900		nm
Range of spectral bandwidth		$\lambda_{0.5}$		600 to 1050		nm
Rise time	$V_R = 20 V, R_L = 50 \Omega, \lambda = 820 \text{ nm}$	t_r		7		ns
Fall time	$V_R = 20 V, R_L = 50 \Omega, \lambda = 820 \text{ nm}$	t_f		7		ns

Note

$T_{amb} = 25^\circ C$, unless otherwise specified

BASIC CHARACTERISTICS

$T_{amb} = 25^\circ C$, unless otherwise specified

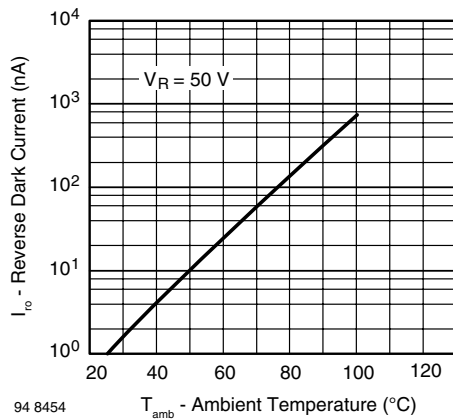


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

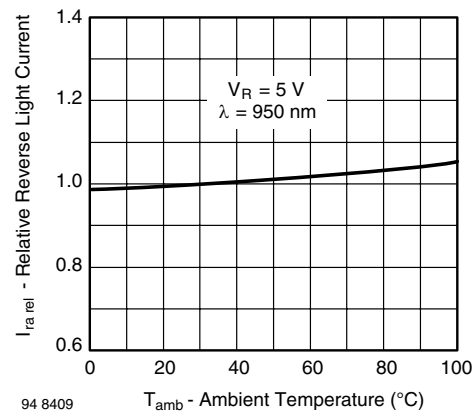
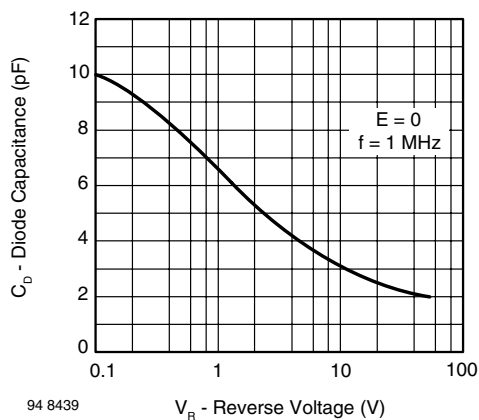
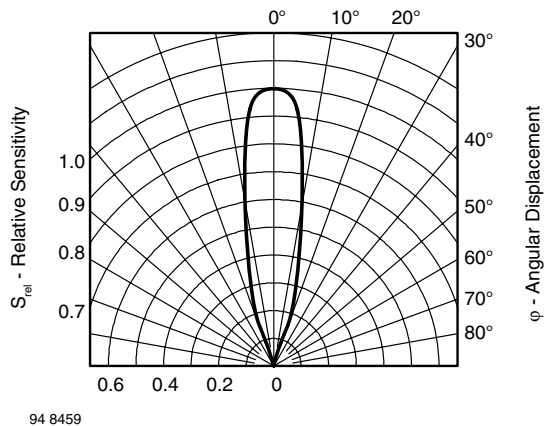
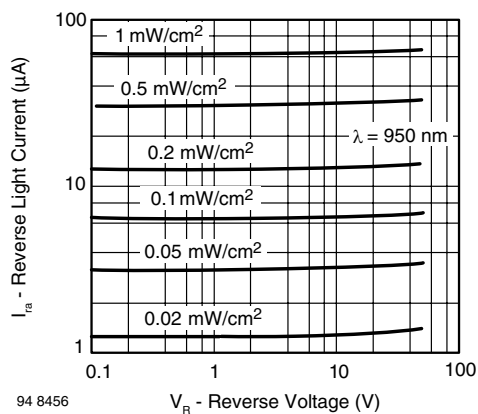
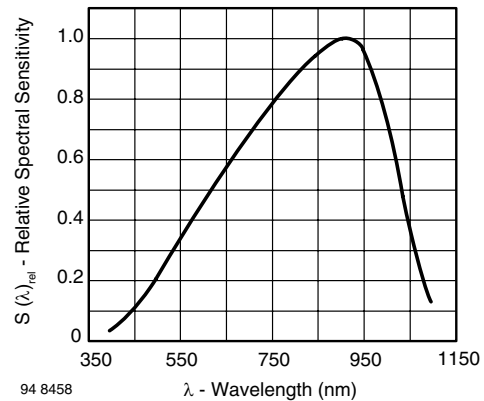
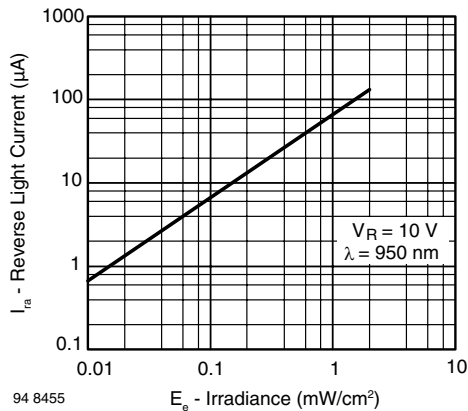
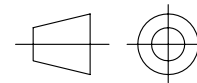
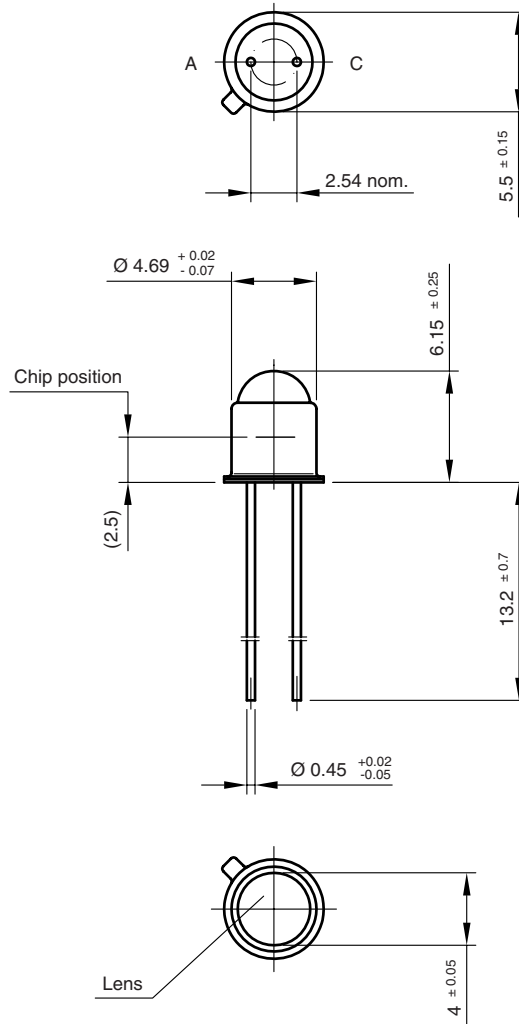


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature



PACKAGE DIMENSIONS in millimeters



technical drawings
according to DIN
specifications

Drawing-No.: 6.503-5022.02-4

Issue: 1; 24.08.98

14487



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